

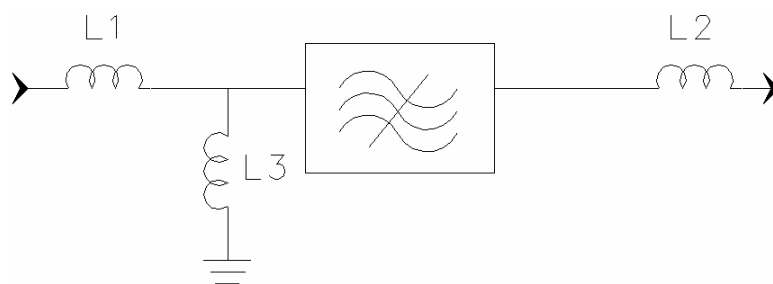
Specifications

Parameter	Unit	Minimum	Typical	Maximum
Center Frequency	MHz	69.9	70	70.1
Insertion Loss	dB		25	26
3 dB Bandwidth	MHz	20.4	20.6	
45 dB Bandwidth	MHz		22.12	22.2
Passband Variation	dB		1	1.5
Absolute Delay	usec		2.4	
Ultimate Rejection	dB	50	52	
Substrate Material		128-LiNbO3		
Ambient Temperature	°C	25		
Package Size		DIP2212 (22.7x12.7x5.2mm ³)		

Notes:

1. All specifications are based on the test circuit shown
2. In production, devices will be tested at room temperature to a guardbanded specification to ensure electrical compliance over temperature
3. Electrical margin has been built into the design to account for the variations due to temperature drift and manufacturing tolerances
4. This is the optimum impedance in order to achieve the performance show

Matching Configuration



$$L1=L2=270\text{nH} \quad L3=330\text{nH}$$

Source/Load Impedance=50 ohm

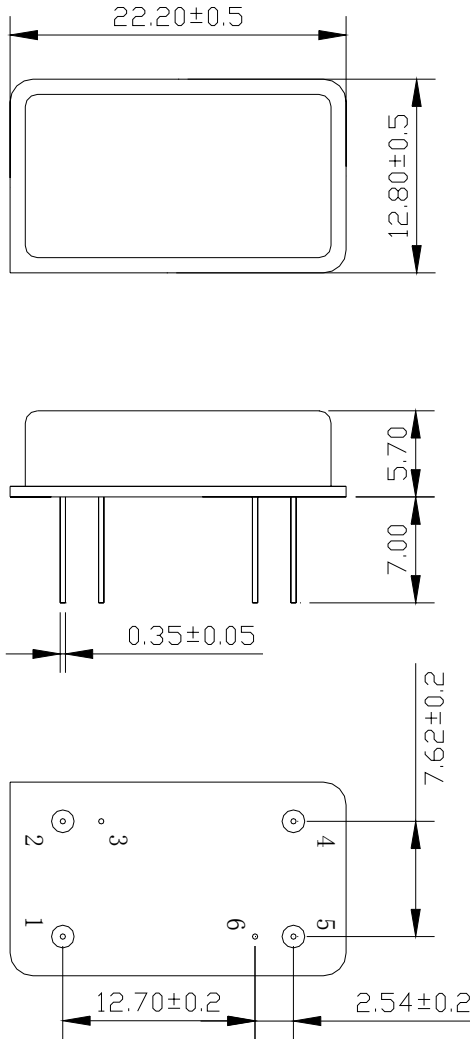
Notes - Component values may change depending
on board layout.



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Package Dimension



Input:1
Output:5



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